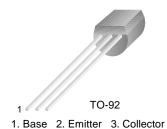


KSP24

VHF Transistor



NPN Epitaxial Silicon Transistor

Absolute Maximum Ratings T_a =25°C unless otherwise noted

Symbol	Parameter	Value	Units
V _{CBO}	Collector-Base Voltage	40	V
V _{CEO}	Collector-Emitter Voltage	30	V
I _{EBO}	Emitter-Base Voltage	4.0	V
I _C	Collector Current	100	mA
l <u>c</u> Pc	Collector Power Dissipation (T _a =25°C)	350	mW
	Derate Above 25°C	2.8	mW/°C
TJ	Junction Temperature	135	°C
T _{STG}	Storage Temperature	-55~150	°C
R _{TH} (j-a)	Thermal Resistance, Junction to Ambient	357	°C/W

Electrical Characteristics T_a =25°C unless otherwise noted

Symbol	Parameter	Test Condition	Min.	Тур.	Max.	Units
BV _{CBO}	Collector-Base Breakdown Voltage	I _C =100μA, I _E =0	40			V
BV _{CEO}	Collector-Emitter Breakdown Voltage	I _C =1mA, I _B =0	30			V
BV _{EBO}	Emitter-Base Breakdown Voltage	I _E =10μA, I _C =0	4.0			V
I _{CBO}	Collector Cut-off Current	V _{CB} =15V, I _E =0			50	nA
h _{FE}	DC Current Gain	V _{CE} =10V, I _C =8mA	30			
f _T	Current Gain Bandwidth Product	V _{CE} =10V, I _C =8mA, f=100MHz	400	620		MHz
C _{ob}	Output Capacitance	V _{CB} =10V, I _E =0, f=1MHz		0.25	0.36	pF
G _{CE}	Conversion Gain (213 to 45MHz)	V _{CC} =20V, I _C =8mA Oscillator Injection=150mV	19	24		dB
G _{CE}	Conversion Gain (60 to 45MHz)	V _{CC} =20V, I _C =8mA Oscillator Injection=150mV	24	29		dB

Typical Characteristics

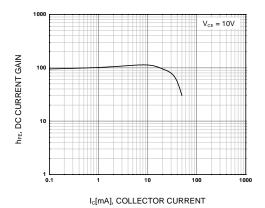


Figure 1. DC current Gain

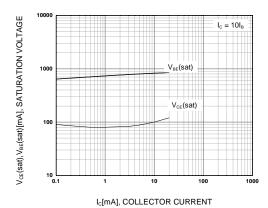


Figure 2. Base-Emitter Saturation Voltage Collector-Emitter Saturation Voltage

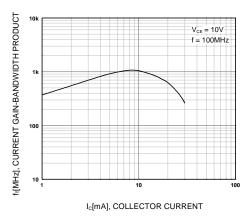


Figure 3. Current Gain Bandwidth Product

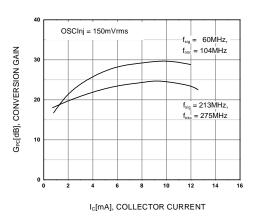


Figure 4. Conversion Gain versus Collector Current

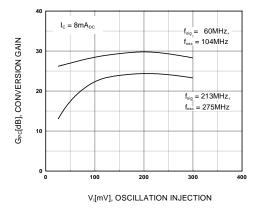


Figure 5. Conversion Gain versus Injection Level

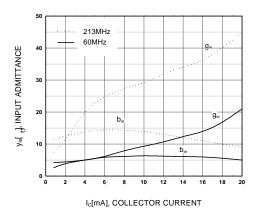


Figure 6. Input Admittance

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Typical Characteristics (Continued)

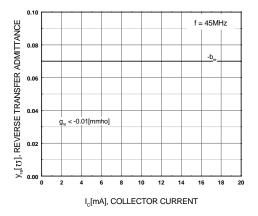


Figure 7. Reverse Transfer Admittance

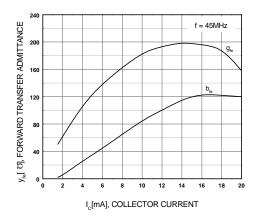


Figure 8. Forward Transfer Admittance

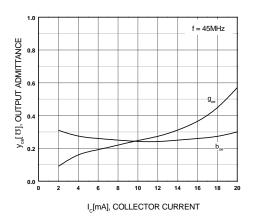
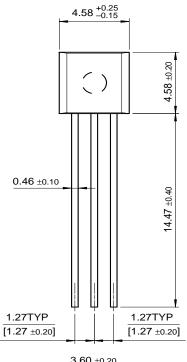


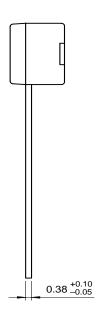
Figure 9. Output Admittance

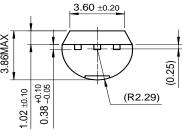
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Package Demensions

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